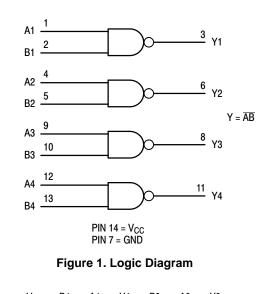
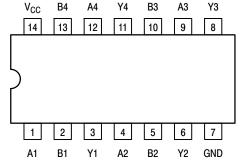
# **Quad 2-Input NAND Gate**

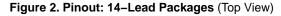
# High–Performance Silicon–Gate CMOS

# Features

- Output Drive Capability: ±24 mA
- Operating Voltage Range: 2 to 6 V AC00; 4.5 to 5.5 ACT00
- Low Input Current: 1.0 µA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance With the JEDEC Standard No. 7A Requirements
- Chip Complexity: 32 FETs
- These are Pb–Free Devices



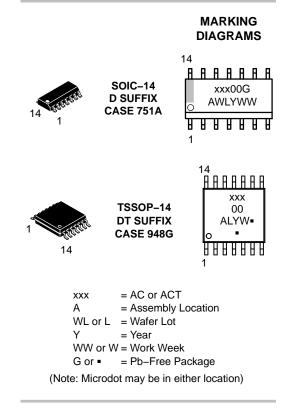






# **ON Semiconductor®**

www.onsemi.com



# FUNCTION TABLE

Inp	uts	Output
Α	в	Y
L	L	Н
L	Н	н
Н	L	н
н	Н	L

# **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \leq V_I \leq V_{CC} + 0.5$	V
V <sub>O</sub>	DC Output Voltage	(Note 1)	$-0.5 \le V_O \le V_{CC} + 0.5$	V
I <sub>IK</sub>	DC Input Diode Current		±20	mA
I <sub>OK</sub>	DC Output Diode Current		±50	mA
I <sub>O</sub>	DC Output Sink/Source Current		±50	mA
I <sub>CC</sub>	DC Supply Current per Output Pin		±50	mA
I <sub>GND</sub>	DC Ground Current per Output Pin		±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead temperature, 1 mm from Case for 10 Se	econds	260	°C
TJ	Junction temperature under Bias		+ 150	°C
$\theta_{JA}$	Thermal Resistance (Note 2)	SOIC TSSOP	125 170	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	SOIC TSSOP	125 170	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 30% – 35%	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	Ŭ	uman Body Model (Note 3) Machine Model (Note 4) ged Device Model (Note 5)	> 2000 > 200 > 1000	V
ILatch-Up	Latch–Up Performance Above V <sub>CC</sub> and Be	elow GND at 85°C (Note 6)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Io absolute maximum rating must be observed.
The package thermal impedance is calculated in accordance with JESD51–7.
Tested to EIA/JESD22–A114–A.

Tested to EIA/JESD22–A115–A.
Tested to JESD22–C101–A.

6. Tested to EIA/JESD78.

# **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Тур	Max	Unit
V <sub>CC</sub>	Supply Voltage	MC74AC00 MC74ACT00	2.0 4.5	5.0 5.0	6.0 5.5	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V <sub>CC</sub>	V
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 7) MC74AC00	V <sub>CC</sub> @ 3.0 V V <sub>CC</sub> @ 4.5 V V <sub>CC</sub> @ 5.5 V	- - -	150 40 25	- - -	ns/V
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 8) MC74ACT00	V <sub>CC</sub> @ 4.5 V V <sub>CC</sub> @ 5.5 V	_	10 8.0	-	ns/V
TJ	Junction Temperature		-	-	150	°C
T <sub>A</sub>	Operating Ambient Temperature Range		-55	25	125	°C
I <sub>OH</sub>	Output Current – High		-	-	-24	mA
I <sub>OL</sub>	Output Current – Low		_	-	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 7.  $V_{in}$  from 30% to 70%  $V_{CC}$ . 8.  $V_{in}$  from 0.8 V to 2.0 V.

#### **DC CHARACTERISTICS**

					MC74AC00			
		v <sub>cc</sub>	T <sub>A</sub> = +	-25°C	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	T <sub>A</sub> = -55°C + 125°C		
Symbol	Parameter	(V)	Тур		Guaranteed	Limits	Unit	Conditions
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	2.1 3.15 3.85	V	$V_{OUT} = 0.1 V$ or V <sub>CC</sub> - 0.1 V
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	0.9 1.35 1.65	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V <sub>OH</sub>	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	2.9 4.4 5.4	V	I <sub>OUT</sub> = -50 μA
		3.0 4.5 5.5	- - -	2.56 3.86 4.86	2.46 3.76 4.76	2.4 3.7 4.7	V	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
V <sub>OL</sub>	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V	I <sub>OUT</sub> = 50 μA
		3.0 4.5 5.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44	0.5 0.5 0.5	V	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0. 1	±1.0	±1.0	μA	$V_{I} = V_{CC}, GND$
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	50	mA	V <sub>OLD</sub> = 1.65 V Max
I <sub>OHD</sub>	Output Current	5.5	-	-	-75	-50	mA	V <sub>OHD</sub> = 3.85 V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	-	4.0	40	40	μΑ	$V_{IN} = V_{CC}$ or GND

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I<sub>IN</sub> and I<sub>CC</sub> @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

# AC CHARACTERISTICS ( $t_r = t_f = 3.0 \text{ nS}$ ; $C_L = 50 \text{ pF}$ ; see Figures 3 and 4 for Waveforms)

			MC74AC00							
		v <sub>cc</sub> *	T <sub>A</sub> = +25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		T <sub>A</sub> = -55°C to + 125°C			
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub>	Propagation Delay	3.3 5.0	2.0 1.5	7.0 6.0	9.5 8.0	2.0 1.5	10.0 8.5	1.0 1.0	11.0 8.5	ns
t <sub>PHL</sub>	Propagation Delay	3.3 5.0	1.5 1.5	5.5 4.5	8.0 6.5	1.0 1.0	8.5 7.0	1.0 1.0	9.0 7.0	ns

\*Voltage Range 3.3 V is 3.3 V  $\pm$  0.3 V.

Voltage Range 5.0 V is 5.0 V  $\pm$  0.5 V.

#### **DC CHARACTERISTICS**

					MC74ACT00			
		Vcc	T <sub>A</sub> = +	-25°C	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	T <sub>A</sub> = -55°C to + 125°C	1	
Symbol	Parameter	(V)	Тур		Guaranteed	Limits	Unit	Conditions
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	2.0 2.0	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	0.8 0.8	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	4.4 5.4	V	I <sub>OUT</sub> = –50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	3.7 4.7	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} -24 \text{ mA}$ -24  mA
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	0.1 0.1	V	I <sub>OUT</sub> = 50 μA
		4.5 5.5	_ _	0.36 0.36	0.44 0.44	0.5 0.5	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $V_{OL}$ 24 mA 24 mA
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	±1.0	μΑ	$V_{I} = V_{CC}, GND$
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6	-	1.5	1.6	mA	$V_{I} = V_{CC} - 2.1 V$
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	50	mA	$V_{OLD}$ = 1.65 V Max
I <sub>OHD</sub>	Output Current	5.5	-	-	-75	-50	mA	V <sub>OHD</sub> = 3.85 V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	-	4.0	40	40	μΑ	$V_{IN} = V_{CC}$ or GND

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

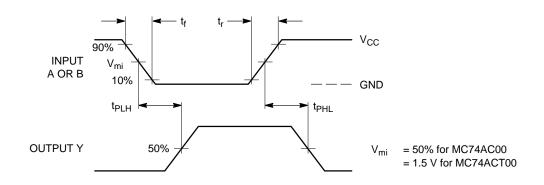
# AC CHARACTERISTICS ( $t_r = t_f = 3.0 \text{ nS}$ ; $C_L = 50 \text{ pF}$ ; see Figures 3 and 4 for Waveforms)

			MC74ACT00							
		V <sub>CC</sub> *	T <sub>A</sub> = +25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		T <sub>A</sub> = -55°C to +125°C			
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub>	Propagation Delay	5.0	1.5	5.5	9.0	1.0	9.5	1.0	9.5	ns
t <sub>PHL</sub>	Propagation Delay	5.0	1.5	4.0	7.0	1.0	8.0	1.0	8.0	ns

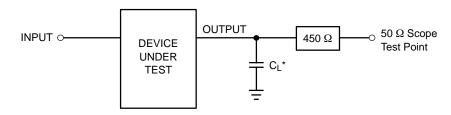
\*Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

# CAPACITANCE

Symbol	Parameter	Value Typ	Test Conditions	Unit
C <sub>IN</sub>	Input Capacitance	4.5	V <sub>CC</sub> = 5.0 V	pF
C <sub>PD</sub>	Power Dissipation Capacitance	30	V <sub>CC</sub> = 5.0 V	pF







\*Includes all probe and jig capacitance

Figure 4. Test Circuit

#### **ORDER INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC74AC00DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC74AC00DR2G	SOIC-14 (Pb-Free)	
MC74AC00DTR2G	TSSOP-14 (Pb-Free)	2500 / Tape and Reel
MC74ACT00DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC74ACT00DR2G	SOIC-14 (Pb-Free)	2500 / Tana and Daal
MC74ACT00DTR2G	TSSOP-14 (Pb-Free)	2500 / Tape and Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# DUSEU

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **STYLES ON PAGE 2**

Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98ASB42565B Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SOIC-14 NB PAGE 1 OF 2 onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

#### SOIC-14 CASE 751A-03 ISSUE L

# DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

DOCUMENT NUMBER:	98ASB42565B	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.					
DESCRIPTION:	SOIC-14 NB		PAGE 2 OF 2				

onsemi and ONSEMI: are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>